NSN 5961-01-408-6789

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-408-6789 **Inclosure Material:** Glass **Overall Length:** 4.8 millimeters **Terminal Length:** 28.0 millimeters **Overall Diameter:** 2.6 millimeters **End Application:** 6625-01-363-6212 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-41 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 24.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 250.00 milliamperes forward current, average blank **Power Rating Per Characteristic:** 1.3 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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